

**JNTUA UNIVERSITY
PREVIOUS QUESTION PAPERS**

B.Tech III Year II Semester (R15) Regular & Supplementary Examinations May/June 2019

INDUSTRIAL ELECTRONICS

(Electronics and Communication Engineering)

Time: 3 hours

Max. Marks: 70

PART – A
(Compulsory Question)

- 1 Answer the following: (10 X 02 = 20 Marks)
- (a) List out any two differences between intrinsic and extrinsic semi conductors.
 - (b) What are the applications of Zener diode?
 - (c) What do you understand by 'Emitter' efficiency?
 - (d) What are the conventions of polarities of voltages and currents?
 - (e) What is half-wave rectifier?
 - (f) What is 'Dynamic emitter resistance'?
 - (g) What is principle involved in 'Induction heating'?
 - (h) What are the electrodes used in 'Dielectric heating'?
 - (i) List out the properties of 'Ultrasonic waves'.
 - (j) What is ultrasonic drying?

PART – B
(Answer all five units, 5 X 10 = 50 Marks)

UNIT – I

- 2 With a neat diagram, explain the operation of LED? Also, give its advantages and applications.

OR

- 3 Discuss in detail the Crystalline structure of semiconductors and also give its properties.

UNIT – II

- 4 Discuss in detail about current components in transistors with necessary diagram.

OR

- 5 Explain the characteristics of CE configuration of PNP junction transistor.

UNIT – III

- 6 Classify the voltage regulators. Also, draw the diagram of bridge rectifier and explain its operation, advantages and limitations.

OR

- 7 What is the principle involved in automatic voltage regulator and discuss about simple DC voltage stabilizer using zener diode.

UNIT – IV

- 8 List out different types of resistance welding and explain in detail about any two of them.

OR

- 9 Explain in detail about the high frequency power source of induction heating.

UNIT – V

- 10 Explain about the physico-chemical effects of ultrasonics and the chemical effects of ultrasonics.

OR

- 11 Discuss the generation of ultrasonic waves and discuss about ultrasonic stroboscope.

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PART – A
(Compulsory Question)

- 1 Answer the following: (10 X 02 = 20 Marks)
- (a) Distinguish between intrinsic semiconductor and extrinsic semiconductor.
 - (b) Explain about majority carriers in n type semiconductors.
 - (c) Define emitter efficiency.
 - (d) Explain about the static characteristic curves of CB configuration.
 - (e) Distinguish between full wave rectifier and bridge rectifier.
 - (f) Give the classification of type of filters.
 - (g) Mention the applications of induction heating.
 - (h) Explain the principle of resistance heating.
 - (i) What are the chemical effects of ultrasonics?
 - (j) Define ultrasonic dying.

PART – B

(Answer all five units, 5 X 10 = 50 Marks)

UNIT – I

- 2 Explain about the formation of PN junction.

OR

- 3 Confer the working of LED and mentions its applications.

UNIT – II

- 4 Explain the working of transistor as an amplifier.

OR

- 5 Explain the input and output characteristics of a transistor in CB configuration.

UNIT – III

- 6 Describe the working of full wave rectifier with and without filters.

OR

- 7 Derive an expression for the ripple factor in a half wave rectifier.

UNIT – IV

- 8 Illustrate the process of resistance welding and energy storage welding.

OR

- 9 Mention the applications of dielectric heating.

UNIT – V

- 10 Discuss about Ultrasonic flaw detection and colloidal effect.

OR

- 11 Contrast about physico-chemical and thermal effects of ultrasonic.
